







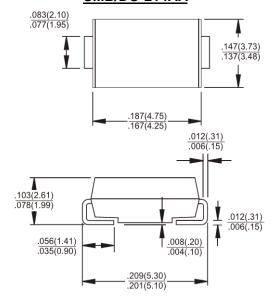
### **Features**

- For surface mounted application
- Glass passivated chip junction
- Low forward voltage drop
- High current capability
- Easy pick and place
- High surge current capability
- Plastic material used carries Underwriters Laboratory Classification 94V-0
- High temperature soldering:  $260^{\circ}$ C/10 seconds at terminals
- Green compound with suffix "G" on packing code & prefix "G" on datecode

### **Mechanical Data**

- Case: Molded plastic
- Terminal: Pure tin plated, lead free
- Polarity: Indicated by cathode band
- Packing: 12mm tape per EIA STD RS-481
- Weight: 0.093 grams

# **S2A - S2M** 2.0 AMPS Surface Mount Rectifiers SMB/DO-214AA



### **Dimensions in inches and (millimeters)**

### **Marking Diagram**

= Specific Device Code G = Green Compound Υ = Year Μ = Work Month

## **Maximum Ratings and Electrical Characteristics**

Rating at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	Symbol	S2A	S2B	S2D	S2G	S2J	S2K	S2M	Unit
Maximum Repetitive Peak Reverse Voltage	$V_{RRM}$	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	$V_{RMS}$	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	$V_{DC}$	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current $@T_L = 100^{\circ}C$	I <sub>F(AV)</sub>	2							Α
Peak Forward Surge Current, 8.3 ms Single Half Sinewave Superimposed on Rated Load (JEDEC method)	I <sub>FSM</sub>	50							Α
Maximum Instantaneous Forward Voltage (Note 1) @ 2 A	V <sub>F</sub>	1.15							V
Maximum Reverse Current @ Rated VR $T_A$ =25 $^{\circ}$ C $T_A$ =125 $^{\circ}$ C	I <sub>R</sub>	1 125							uA
Maximum Reverse Recovery Time (Note 2)	Trr	1.5							uS
Typical Junction Capacitance (Note 3)	Cj	30							pF
Typical Thermal Resistance	R <sub>θjA</sub> R <sub>θjL</sub>	53 16						°C/W	
Operating Temperature Range	TJ	- 55 to + 150						οС	
Storage Temperature Range	T <sub>STG</sub>	- 55 to + 150						οС	

Note 1: Pulse Test with PW=300 usec, 1% Duty Cycle

Note 2: Reverse Recovery Test Conditions:  $I_F$ =0.5A,  $I_R$ =1.0A,  $I_{RR}$ =0.25A

Note 3: Measured at 1 MHz and Applied Reverse Voltage of 4.0V D.C.



### RATINGS AND CHARACTERISTIC CURVES (S2A THRU S2M)

